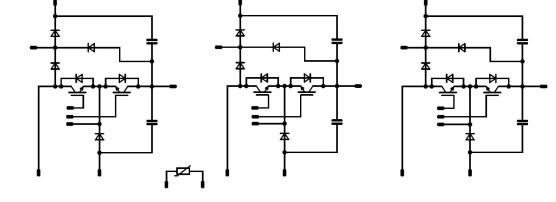




Vincotech

flow3xANPFC 1		650 V / 30 A
Features		flow 1 12 mm housing
<ul style="list-style-type: none">• 3xAdvanced Neutral Boost PFC• Integrated DC capacitor• Kelvin Emitter for improved switching performance		
Target applications		Schematic
<ul style="list-style-type: none">• Charging Stations• Power Supply		
Types		
<ul style="list-style-type: none">• 10-FY073AA030RG02-LK12L08		



10-FY073AA030RG02-LK12L08

datasheet

Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Negative Neutral Point Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	36	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	120	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	63	W
Gate-emitter voltage	V_{GES}		± 30	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Positive Neutral Point Switch

Collector-emitter voltage	V_{CES}		650	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	36	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	120	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	63	W
Gate-emitter voltage	V_{GES}		± 30	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Negative Boost Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Positive Boost Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



10-FY073AA030RG02-LK12L08

datasheet

Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Negative Neutral Point Diode				
Peak repetitive reverse voltage	V_{RRM}		1600	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$	36	A
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$	270	A
Surge current capability	I^P_t		360	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	46	W
Maximum junction temperature	T_{jmax}		150	$^\circ\text{C}$

Positive Neutral Point Diode

Peak repetitive reverse voltage	V_{RRM}		1600	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$	36	A
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$	270	A
Surge current capability	I^P_t		360	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	46	W
Maximum junction temperature	T_{jmax}		150	$^\circ\text{C}$

Positive Boost Diode Protection Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$	17	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	33	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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datasheet

Vincotech

Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Positive Boost Blocking Diode				
Peak repetitive reverse voltage	V_{RRM}		1600	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$	36	A
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$	270	A
Surge current capability	P_t	$T_j = 150 \text{ }^\circ\text{C}$	360	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	46	W
Maximum junction temperature	T_{jmax}		150	$^\circ\text{C}$

Capacitor (DC)

Maximum DC voltage	V_{MAX}		500	V
Operation Temperature	T_{op}		-55 ... 125	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
Isolation voltage	V_{isol}	AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				>12,7	mm
Clearance				8,9	mm
Comparative Tracking Index	CTI			≥ 200	

*100 % tested in production



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Negative Boost Diode

Static

Forward voltage	V_F				20	25 125 150		2,25 2,04 1,9	2,6 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 650$ V			25			10	μA	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						2,52		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

Dynamic

Peak recovery current	I_{RRM}	$di/dt=3911$ A/μs $di/dt=3595$ A/μs	± 15	400	30	25		34,1 41,56 44,05		A
Reverse recovery time	t_{rr}					25		33,99 48,13 78,92		ns
Recovered charge	Q_r					25		0,489 1 1,23		μC
Reverse recovered energy	E_{rec}					25		0,139 0,292 0,366		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25		7174 1551 1461		A/μs



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datasheet

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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Positive Boost Diode

Static

Forward voltage	V_F				20	25 125 150		2,25 2,04 1,9	2,6 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 650$ V			25			10	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						2,52		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

Dynamic

Peak recovery current	I_{RRM}	$di/dt=3270$ A/ μ s $di/dt=3480$ A/ μ s $di/dt=3260$ A/ μ s	± 15	400	30	25 125 150		35,17 43,65 46,86		A
Reverse recovery time	t_{rr}					25 125 150		23,3 40,4 43,4		ns
Recovered charge	Q_r					25 125 150		0,435 0,96 1,13		μ C
Reverse recovered energy	E_{rec}					25 125 150		0,144 0,312 0,364		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		2120 2870 2960		A/μ s

**10-FY073AA030RG02-LK12L08**

datasheet

Vincotech**Characteristic Values**

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	

Negative Neutral Point Diode**Static**

Forward voltage	V_F				30	25 125 150		1,24 1,22	1,29 ⁽¹⁾ 1,26 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 1600$ V				25 150			10 1	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,51		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

Positive Neutral Point Diode**Static**

Forward voltage	V_F				30	25 125 150		1,24 1,22	1,29 ⁽¹⁾ 1,26 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 1600$ V				25 150			10 1	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,51		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----



10-FY073AA030RG02-LK12L08

datasheet

Vincotech

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	T_j [°C]	Min	Typ	Max

Thermistor

Static

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$A_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P							5		mW
Power dissipation constant	d					25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3962		K
B-value	$B_{(25/100)}$	Tol. ±1 %						4000		K
Vincotech Thermistor Reference									I	

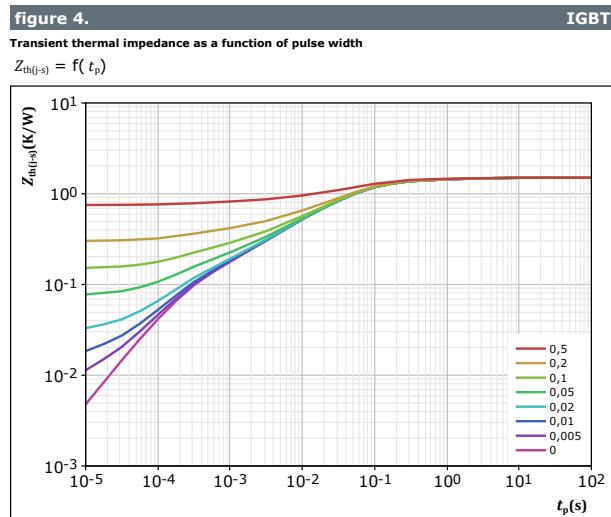
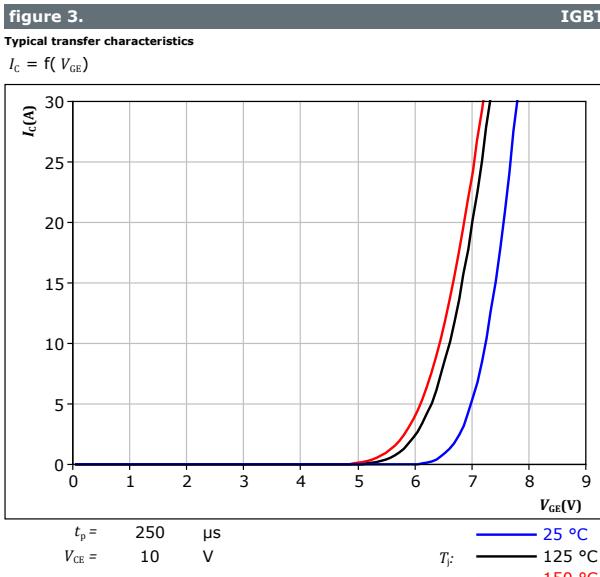
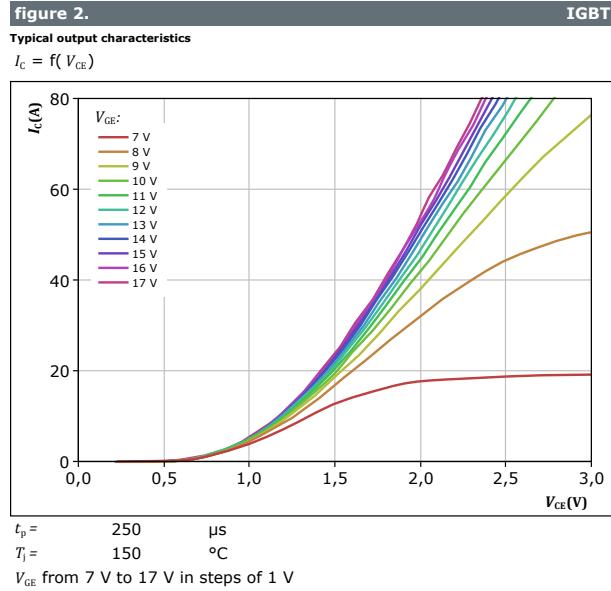
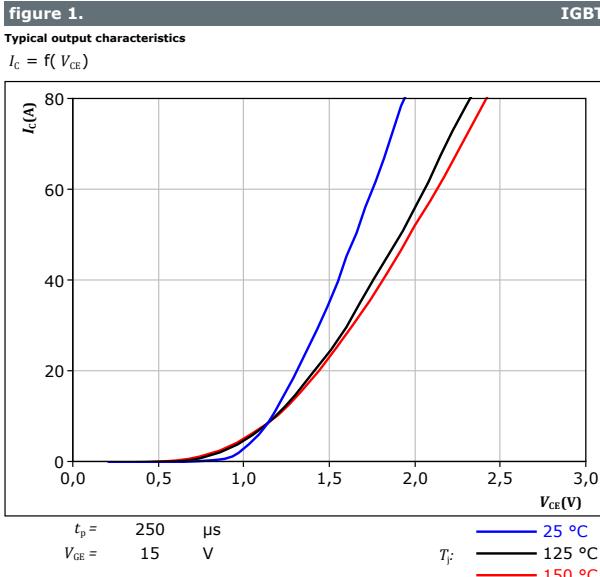
(1) Value at chip level

(2) Only valid with pre-applied Vincotech thermal interface material.



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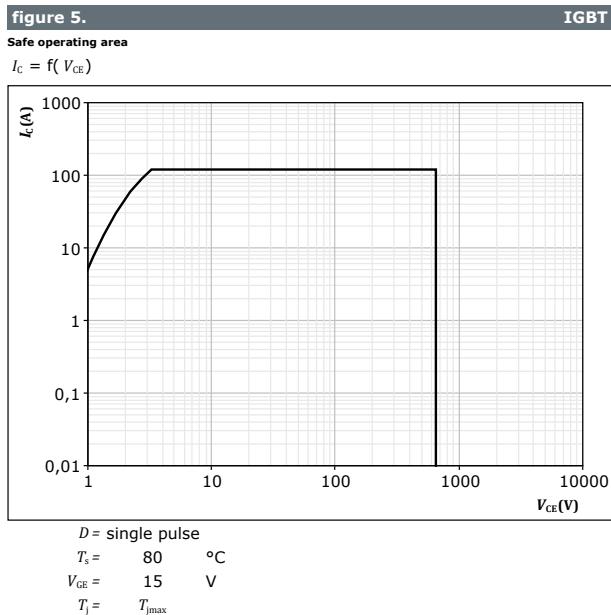
Negative Neutral Point Switch Characteristics





Vincotech

Negative Neutral Point Switch Characteristics





Vincotech

Positive Neutral Point Switch Characteristics

figure 6. IGBT

Typical output characteristics
 $I_C = f(V_{CE})$

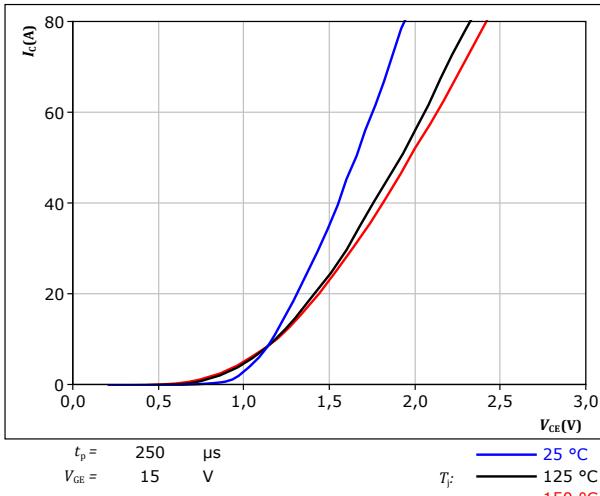


figure 7. IGBT

Typical output characteristics
 $I_C = f(V_{CE})$

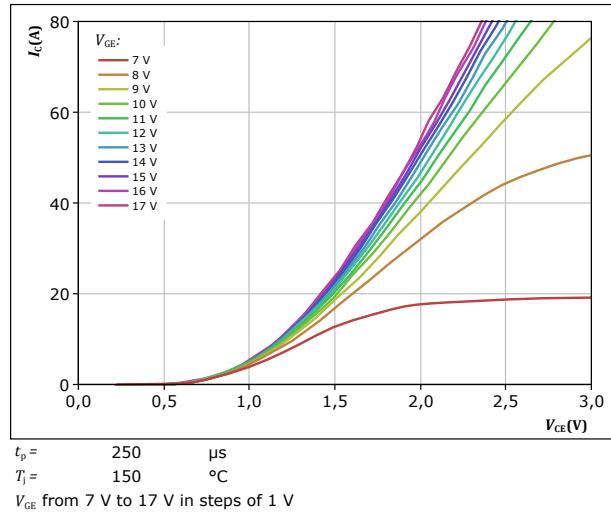


figure 8. IGBT

Typical transfer characteristics
 $I_C = f(V_{GE})$

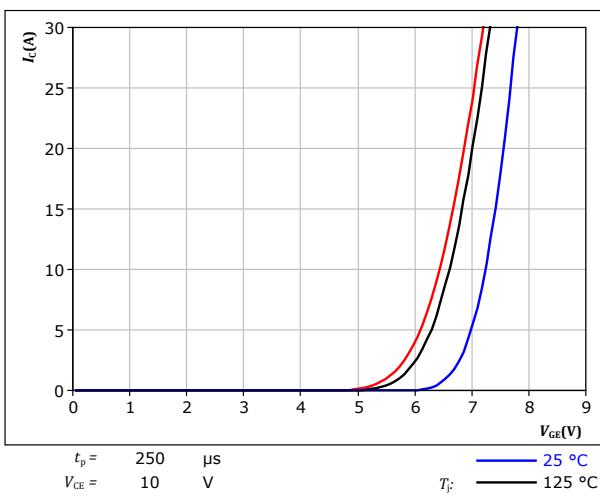
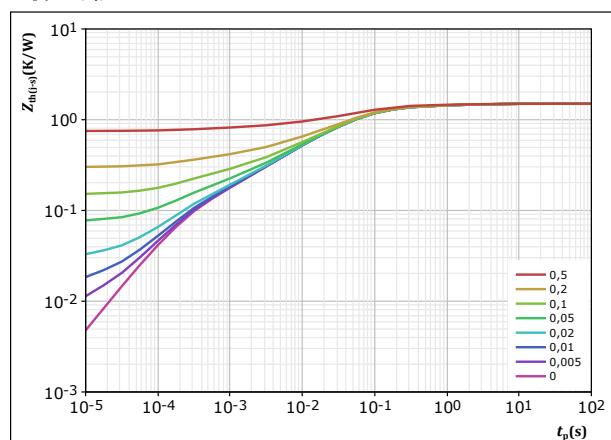


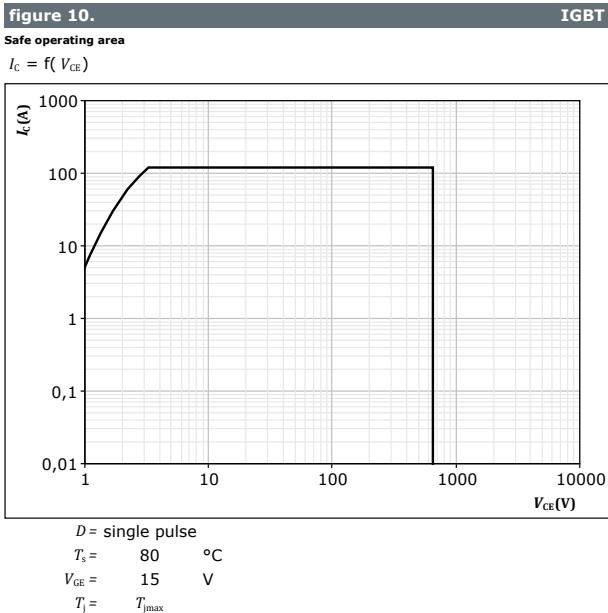
figure 9. IGBT

Transient thermal impedance as a function of pulse width
 $Z_{th(j-s)} = f(t_p)$





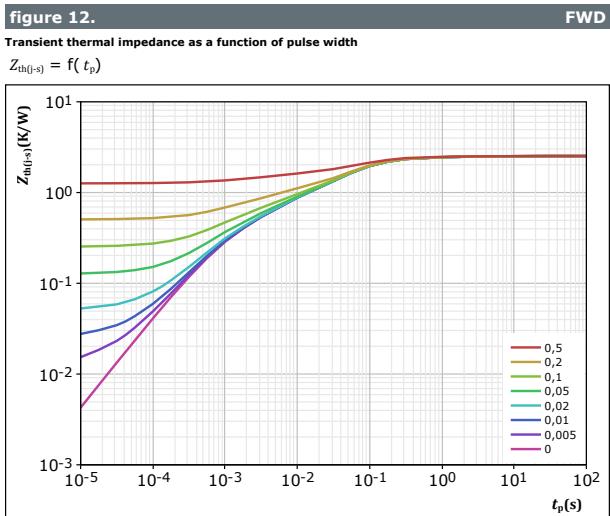
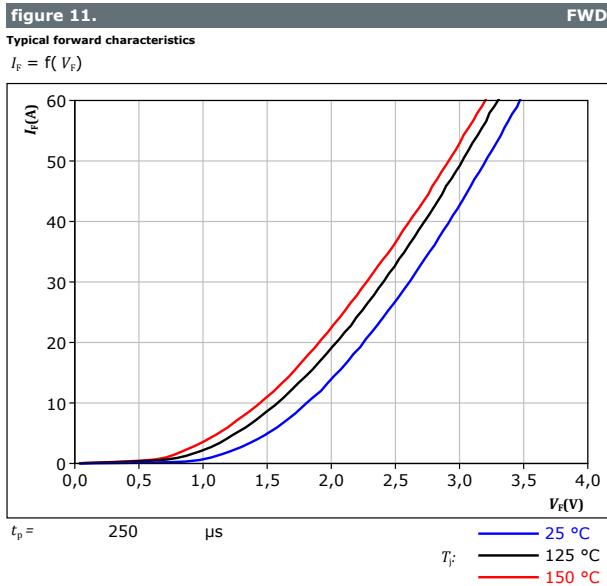
Positive Neutral Point Switch Characteristics





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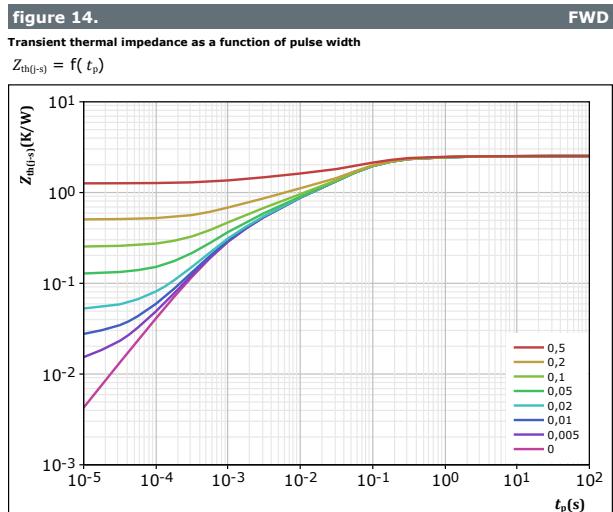
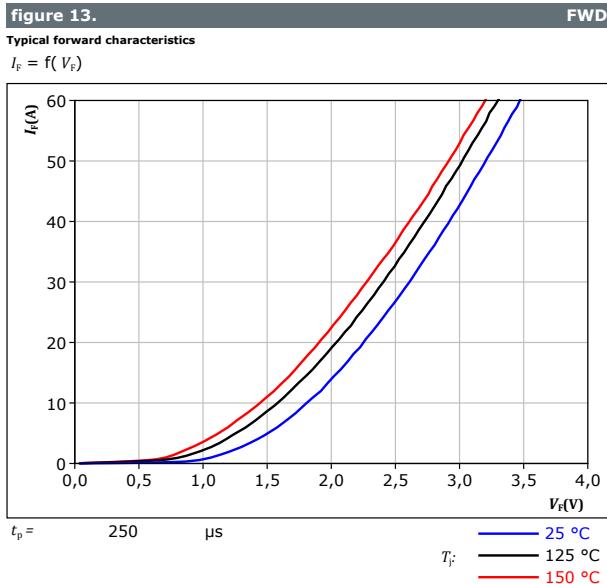
Negative Boost Diode Characteristics





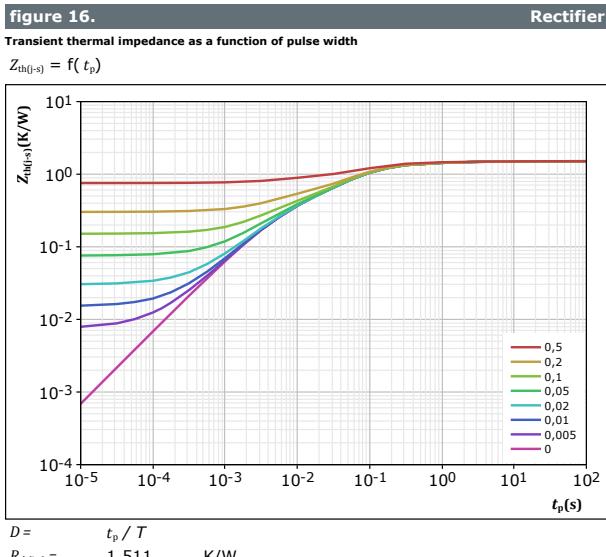
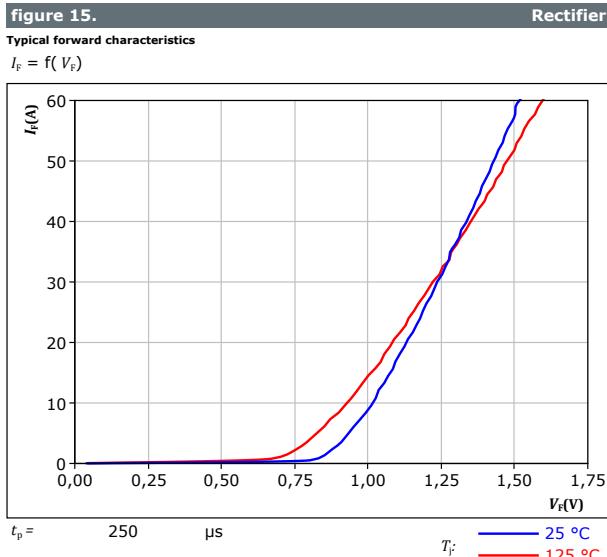
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Positive Boost Diode Characteristics





Negative Neutral Point Diode Characteristics





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Positive Neutral Point Diode Characteristics

figure 17.

Typical forward characteristics

$$I_F = f(V_F)$$

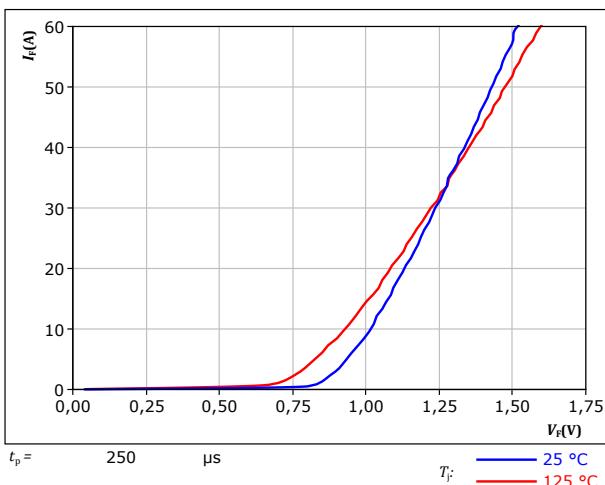
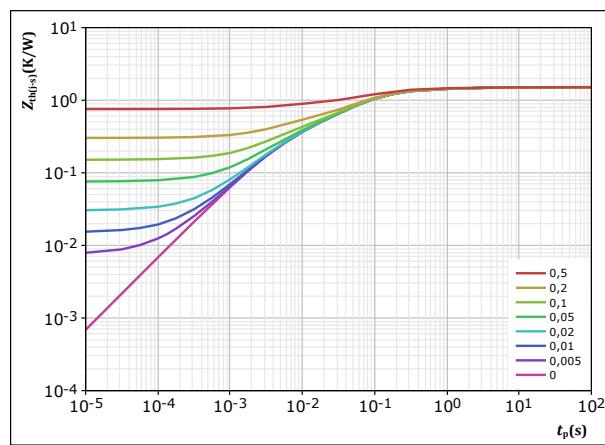


figure 18.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$$D = \frac{t_p / T}{1,511} \quad K/W$$

Rectifier thermal model values

$R (K/W)$	$\tau (s)$
3,93E-02	9,06E+00
1,22E-01	9,78E-01
5,85E-01	1,29E-01
5,38E-01	3,98E-02
2,27E-01	4,50E-03



Positive Boost Diode Protection Diode Characteristics

figure 19.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD

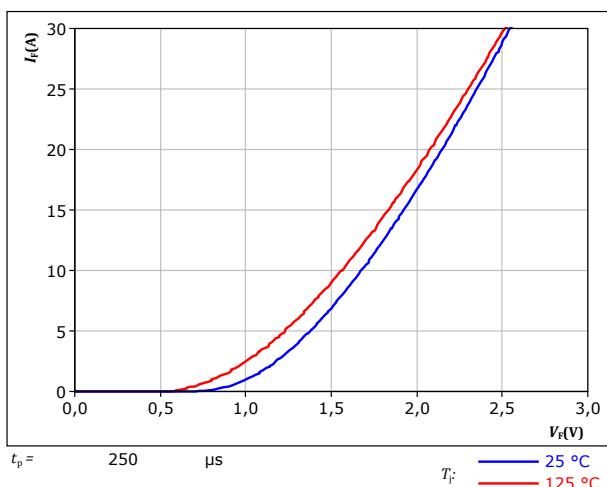
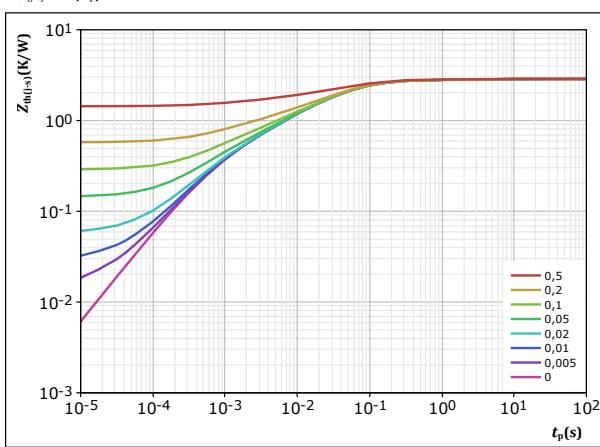


figure 20.

Transient thermal impedance as a function of pulse width

$$Z_{th(t-s)} = f(t_p)$$

FWD



$$D = \frac{t_p / T}{2,873} \quad K/W$$

FWD thermal model values

R (K/W)	τ (s)
6,53E-02	3,94E+00
1,48E-01	4,48E-01
1,31E+00	5,96E-02
7,32E-01	1,36E-02
4,04E-01	2,79E-03
2,11E-01	5,37E-04

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datasheet

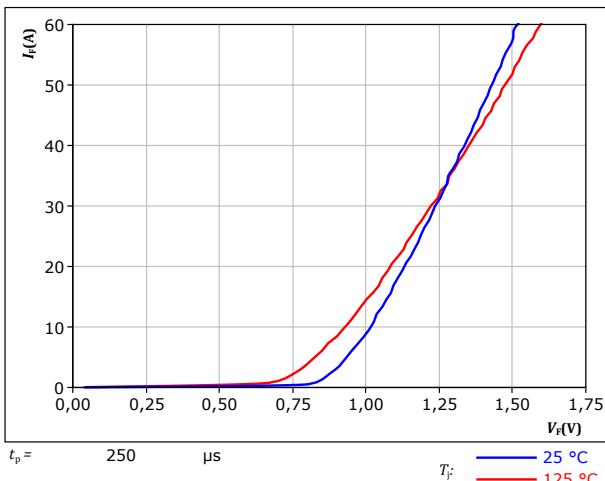
Vincotech

Positive Boost Blocking Diode Characteristics

figure 21.

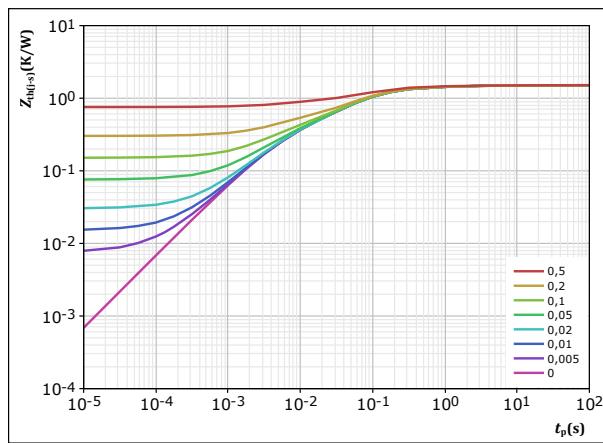
Typical forward characteristics

$$I_F = f(V_F)$$

**Rectifier****figure 22.**

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

**Rectifier**

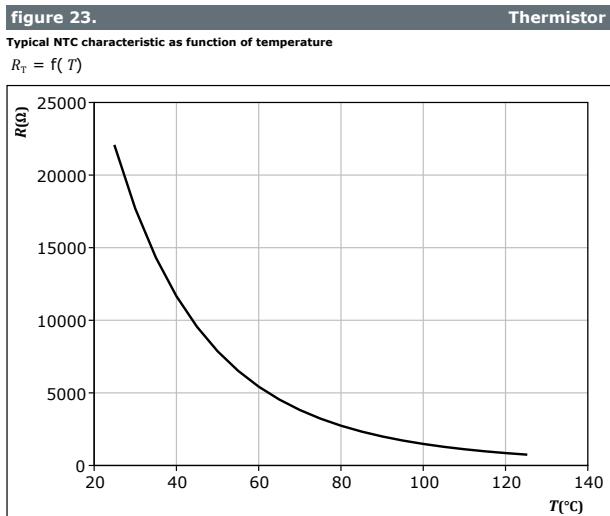
$$D = \frac{t_p / T}{1,511} \quad R_{th(j-s)} = \frac{1}{K/W}$$

Rectifier thermal model values

R (K/W)	τ (s)
3,93E-02	9,06E+00
1,22E-01	9,78E-01
5,85E-01	1,29E-01
5,38E-01	3,98E-02
2,27E-01	4,50E-03



Thermistor Characteristics





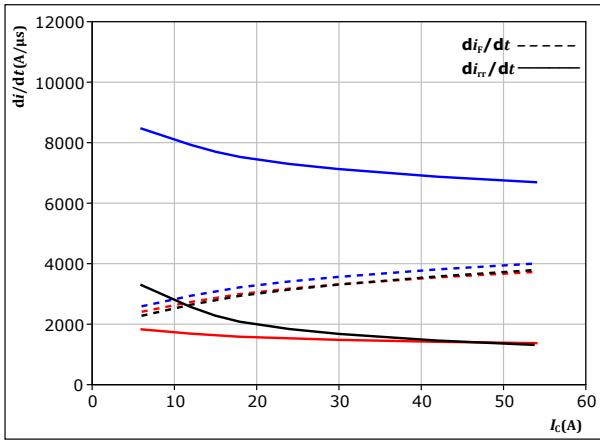
Vincotech

Negative Neutral Point Switching Characteristics

figure 36. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at

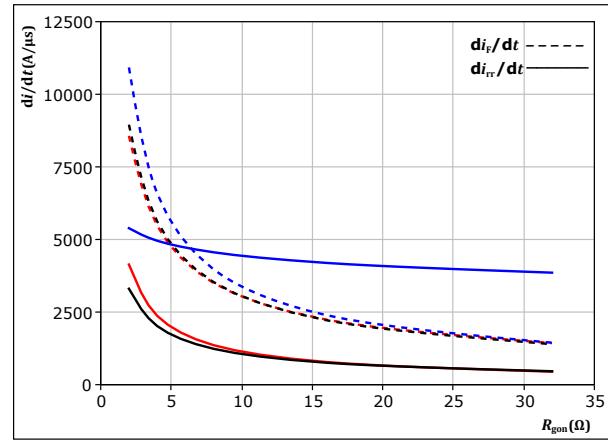
$V_{CE} = 400 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 8 \Omega$

$T_j = 25^\circ\text{C}$ (blue)
 $T_j = 125^\circ\text{C}$ (black)
 $T_j = 150^\circ\text{C}$ (red)

figure 37. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor

$di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

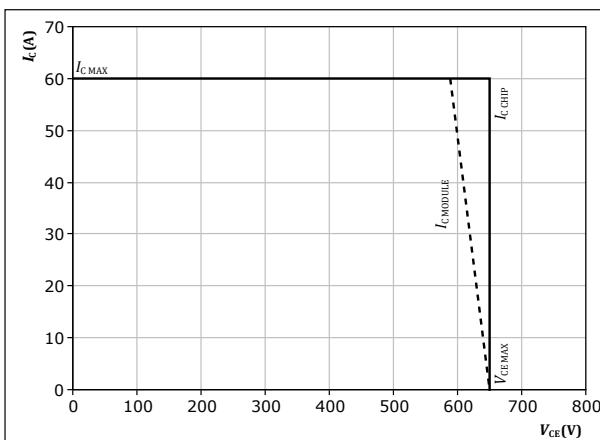
$V_{CE} = 400 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_c = 30 \text{ A}$

$T_j = 25^\circ\text{C}$ (blue)
 $T_j = 125^\circ\text{C}$ (black)
 $T_j = 150^\circ\text{C}$ (red)

figure 38. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At $T_j = 150^\circ\text{C}$
 $R_{gon} = 8 \Omega$
 $R_{goff} = 8 \Omega$



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datasheet

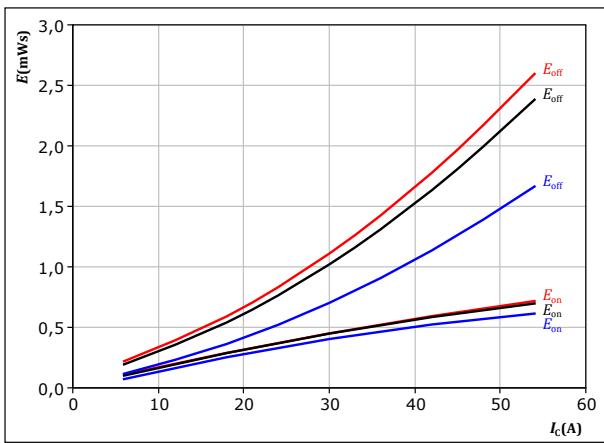
Vincotech

Positive Neutral Point Switching Characteristics

figure 39.

Typical switching energy losses as a function of collector current

$$E = f(I_c)$$



IGBT

IGBT

figure 40.

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$

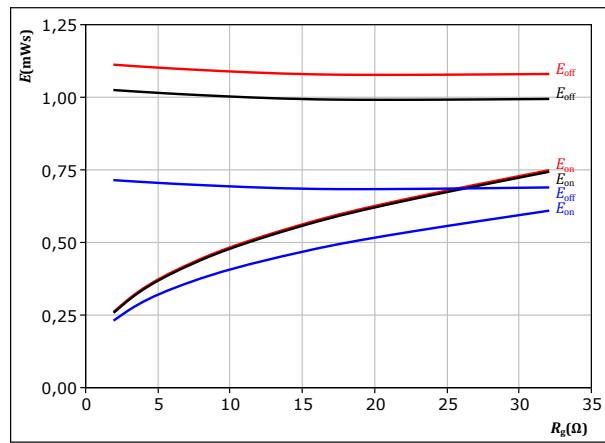
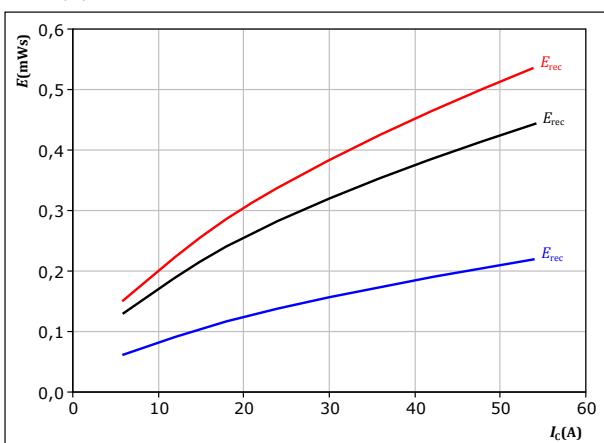


figure 41.

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_c)$$



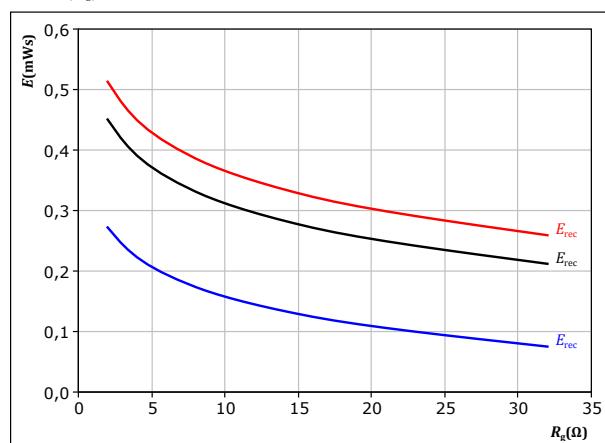
FWD

FWD

figure 42.

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



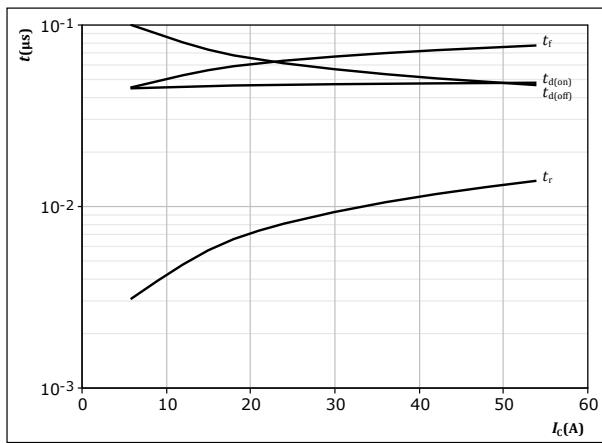


Vincotech

Positive Neutral Point Switching Characteristics

figure 43.

Typical switching times as a function of collector current
 $t = f(I_C)$



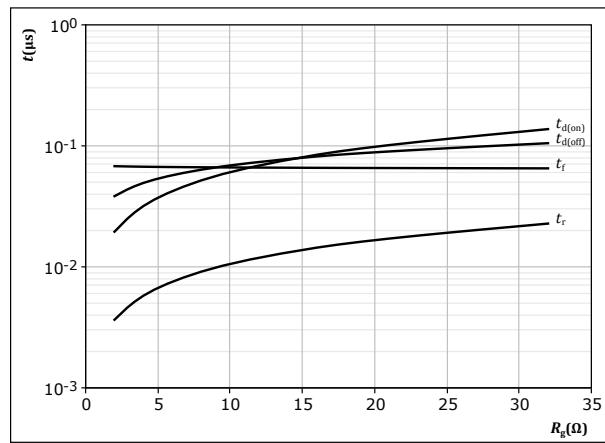
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 400 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 8 \Omega$
 $R_{goff} = 8 \Omega$

IGBT

figure 44.

Typical switching times as a function of gate resistor
 $t = f(R_g)$



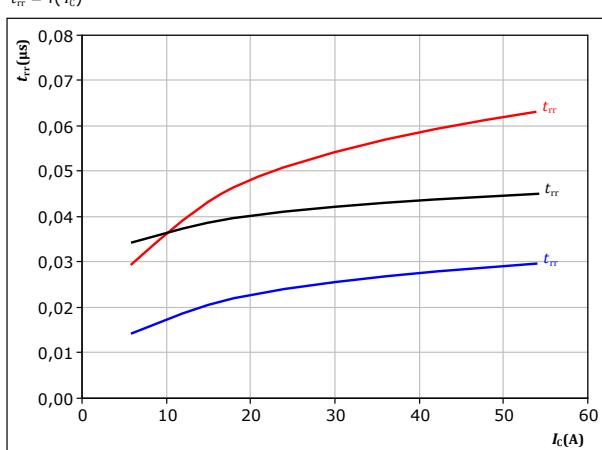
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 400 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 30 \text{ A}$

IGBT

figure 45.

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



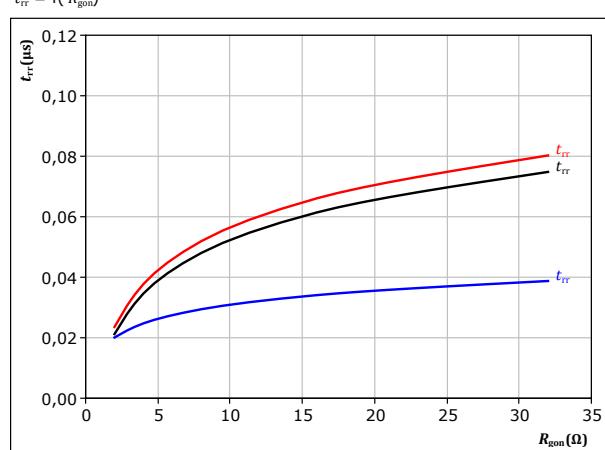
With an inductive load at

$V_{CE} = 400 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 8 \Omega$

FWD

figure 46.

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 400 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 30 \text{ A}$

FWD

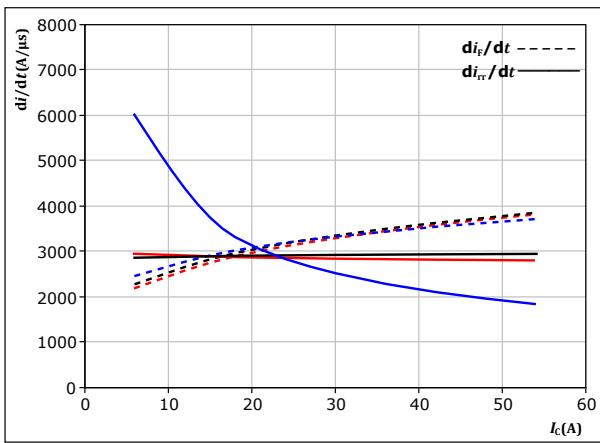


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Positive Neutral Point Switching Characteristics

figure 51. FWD

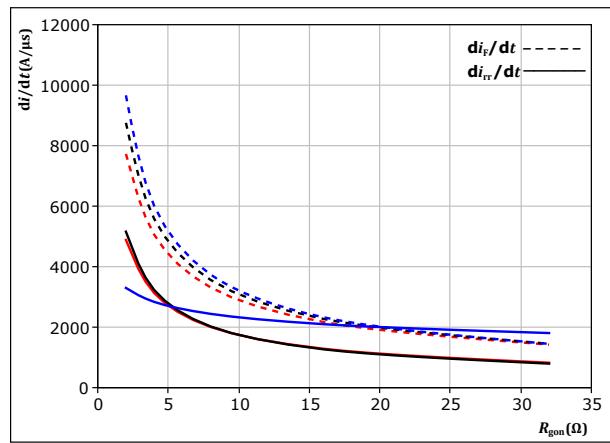
Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at
 $V_{CE} = 400 \text{ V}$ $T_j = 25^\circ\text{C}$
 $V_{GE} = \pm 15 \text{ V}$ $T_j = 125^\circ\text{C}$
 $R_{gon} = 8 \Omega$ $T_j = 150^\circ\text{C}$

figure 52. FWD

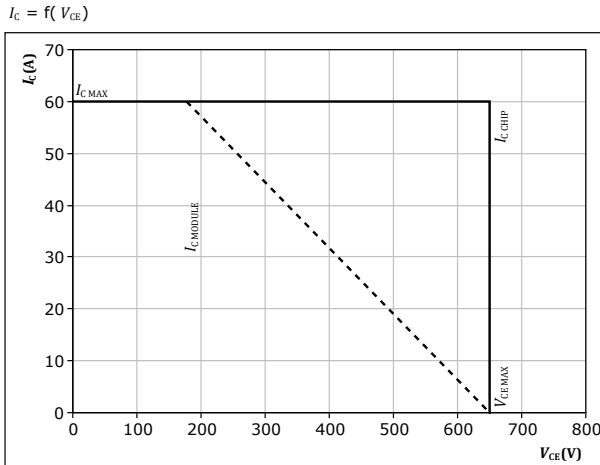
Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at
 $V_{CE} = 400 \text{ V}$ $T_j = 25^\circ\text{C}$
 $V_{GE} = \pm 15 \text{ V}$ $T_j = 125^\circ\text{C}$
 $I_c = 30 \text{ A}$ $T_j = 150^\circ\text{C}$

figure 53. IGBT

Reverse bias safe operating area
 $I_c = f(V_{CE})$



At $T_j = 150^\circ\text{C}$
 $R_{gon} = 8 \Omega$
 $R_{goff} = 8 \Omega$



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Switching Definitions

figure 54. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

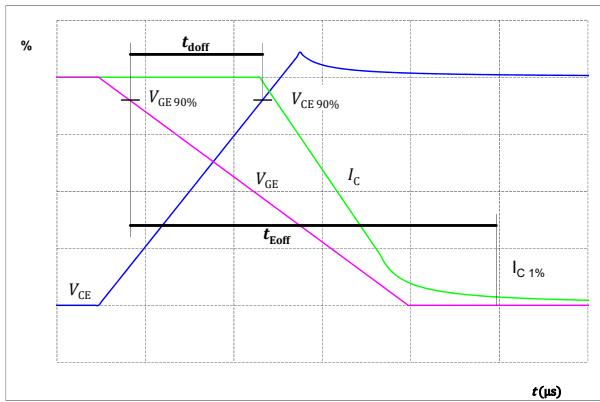


figure 56. IGBT

Turn-off Switching Waveforms & definition of t_f

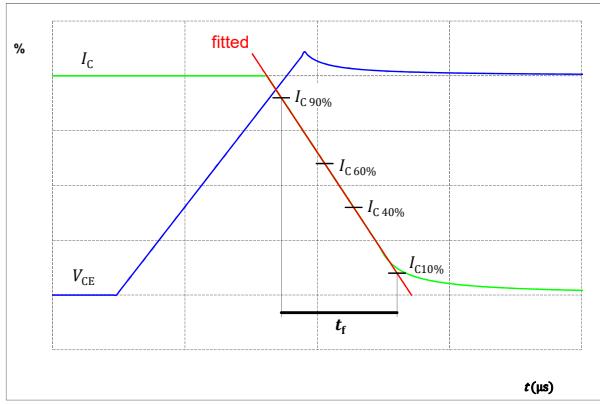


figure 55. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

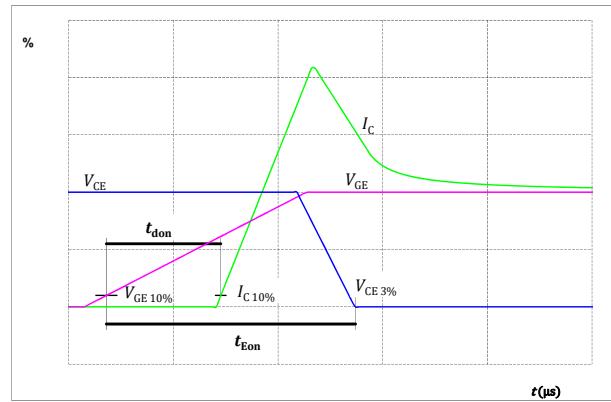
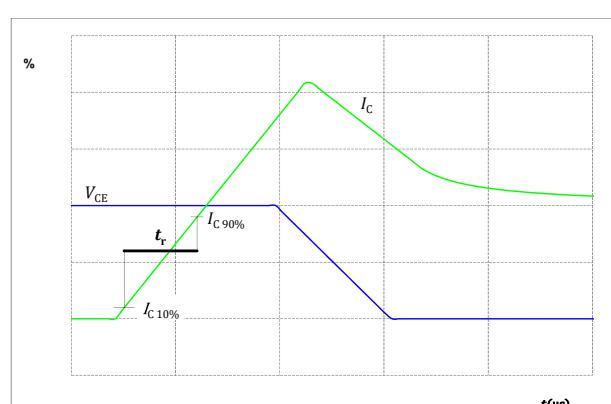


figure 57. IGBT

Turn-on Switching Waveforms & definition of t_r





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Switching Definitions

figure 58.

Turn-off Switching Waveforms & definition of t_{tr}

FWD

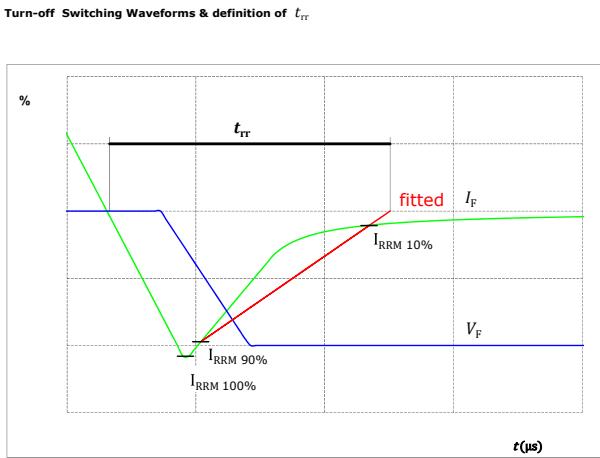
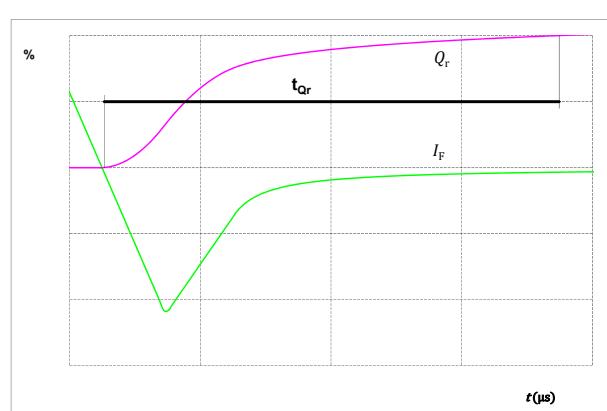


figure 59.

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

FWD



**10-FY073AA030RG02-LK12L08**

datasheet

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Ordering Code																																																																																																																	
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<table border="1"><caption>Pin table [mm]</caption><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>52,9</td><td>0</td><td>TM61</td></tr><tr><td>2</td><td>42,35</td><td>0</td><td>Ph3</td></tr><tr><td>3</td><td>34,25</td><td>0</td><td>TM51</td></tr><tr><td>4</td><td>23,7</td><td>0</td><td>Ph2</td></tr><tr><td>5</td><td>15,7</td><td>0</td><td>TM41</td></tr><tr><td>6</td><td>7,9</td><td>0</td><td>Ph1</td></tr><tr><td>7</td><td>0</td><td>0</td><td>Therm1</td></tr><tr><td>8</td><td>0</td><td>3</td><td>Therm2</td></tr><tr><td>9</td><td>2</td><td>15,65</td><td>DC-1</td></tr><tr><td>10</td><td>6,35</td><td>28,9</td><td>G14</td></tr><tr><td>11</td><td>9,35</td><td>28,9</td><td>G13</td></tr><tr><td>12</td><td>7,85</td><td>25,9</td><td>S1</td></tr><tr><td>13</td><td>24,9</td><td>28,9</td><td>G24</td></tr><tr><td>14</td><td>27,9</td><td>28,9</td><td>G23</td></tr><tr><td>15</td><td>26,4</td><td>25,9</td><td>S2</td></tr><tr><td>16</td><td>43,55</td><td>28,9</td><td>G34</td></tr><tr><td>17</td><td>46,55</td><td>28,9</td><td>G33</td></tr><tr><td>18</td><td>45,05</td><td>25,9</td><td>S3</td></tr><tr><td>19</td><td>52,75</td><td>9,35</td><td>DC+3</td></tr><tr><td>20</td><td>45,4</td><td>11,4</td><td>GND3</td></tr><tr><td>21</td><td>39,2</td><td>15,65</td><td>DC-3</td></tr><tr><td>22</td><td>34,1</td><td>9,35</td><td>DC+2</td></tr><tr><td>23</td><td>26,75</td><td>11,4</td><td>GND2</td></tr><tr><td>24</td><td>20,55</td><td>15,65</td><td>DC-2</td></tr><tr><td>25</td><td>15,55</td><td>9,35</td><td>DC+1</td></tr><tr><td>26</td><td>8,2</td><td>11,4</td><td>GND1</td></tr></tbody></table>	Pin	X	Y	Function	1	52,9	0	TM61	2	42,35	0	Ph3	3	34,25	0	TM51	4	23,7	0	Ph2	5	15,7	0	TM41	6	7,9	0	Ph1	7	0	0	Therm1	8	0	3	Therm2	9	2	15,65	DC-1	10	6,35	28,9	G14	11	9,35	28,9	G13	12	7,85	25,9	S1	13	24,9	28,9	G24	14	27,9	28,9	G23	15	26,4	25,9	S2	16	43,55	28,9	G34	17	46,55	28,9	G33	18	45,05	25,9	S3	19	52,75	9,35	DC+3	20	45,4	11,4	GND3	21	39,2	15,65	DC-3	22	34,1	9,35	DC+2	23	26,75	11,4	GND2	24	20,55	15,65	DC-2	25	15,55	9,35	DC+1	26	8,2	11,4	GND1					
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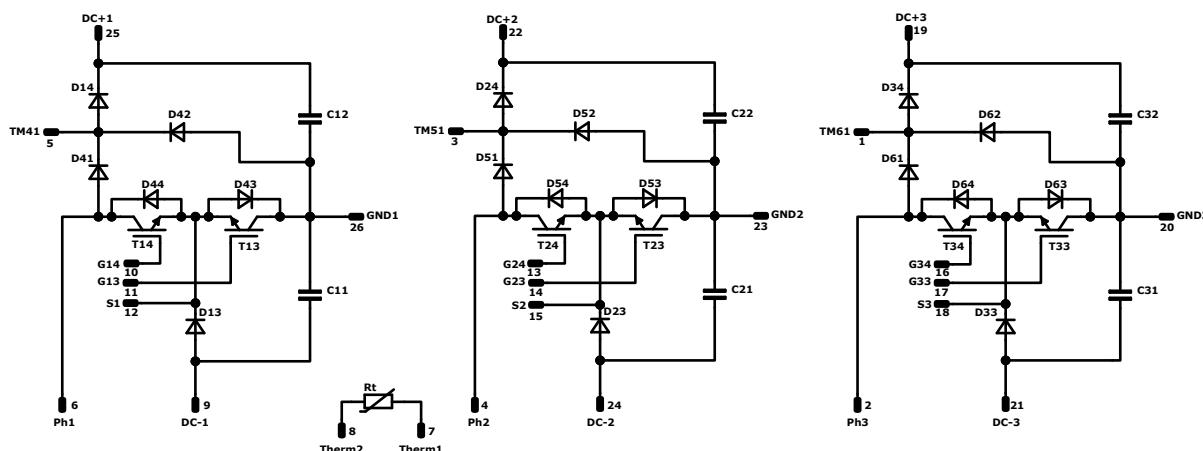


10-FY073AA030RG02-LK12L08

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Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T13, T23, T33	IGBT	650 V	30 A	Negative Neutral Point Switch	
T14, T24, T34	IGBT	650 V	30 A	Positive Neutral Point Switch	
D13, D23, D33	FWD	650 V	20 A	Negative Boost Diode	
D14, D24, D34	FWD	650 V	20 A	Positive Boost Diode	
D43, D53, D63	Rectifier	1600 V	20 A	Negative Neutral Point Diode	
D44, D54, D64	Rectifier	1600 V	20 A	Positive Neutral Point Diode	
D42, D52, D62	FWD	650 V	10 A	Positive Boost Diode Protection Diode	
D41, D51, D61	Rectifier	1600 V	20 A	Positive Boost Blocking Diode	
C11, C12, C21, C22, C31, C32	Capacitor	500 V		Capacitor (DC)	
Rt	Thermistor			Thermistor	

**10-FY073AA030RG02-LK12L08**

datasheet

Vincotech**Packaging instruction**

Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample
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Handling instruction

Handling instructions for flow 1 packages see vincotech.com website.

Package data

Package data for flow 1 packages see vincotech.com website.

Vincotech thermistor reference

See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number

This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-FY073AA030RG02-LK12L08-D1-14	26 Jan. 2021		

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